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MEMC 98-5751 (2358.4)
PATENT

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of Mutti et al.

Serial No. 10/008,812

Filed November 13, 2001

For METHOD FOR CONTROLLING GROWTH OF A SILICON CRYSTAL TO MINIMIZE
GROWTH RATE AND DIAMETER DEVIATIONS

November 20, 2003

LETTER TO THE OFFICIAL DRAFTSMAN

TO THE COMMISSIONER FOR PATENTS,

SIR:

Submitted herewith are five (5) sheets of formal drawings to replace the drawings now on
file.

The Commissioner is hereby authorized to charge any fees that may be required during
the entire pendency of this application to Deposit Account No. 19-1345.

Respectfully submitted,

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